## NSN 5961-01-340-0679

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View Online at https://aerobasegroup.com/nsn/5961-01-340-0679 **Inclosure Material:** Metal **Overall Length:** 0.290 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **End Application:** Test set guided missile an/dsm-127-4 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Response Time:** 70.0 nanoseconds **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 forward voltage, dc **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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